

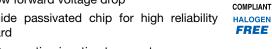
# **Ultrafast Soft Recovery Diode,** 30 A FRED Pt® Gen 4



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	30 A					
$V_{R}$	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.19 V					
t <sub>rr</sub> typ.	see Recovery table					
T <sub>J</sub> max.	175 °C					
Package	TO-247AD 2L					
Circuit configuration	Single					

#### **FEATURES**

- Gen 4 FRED Pt® technology
- Low I<sub>RRM</sub> and reverse recovery charge
- · Very low forward voltage drop
- · Polyimide passivated chip for high reliability standard



- 175 °C operating junction temperature
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

#### **DESCRIPTION**

Gen 4 Fred technology, state of the art, ultralow V<sub>F</sub>, soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Peak repetitive reverse voltage	$V_{RRM}$		600	V		
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 131 °C	30	۸		
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_C = 25$ °C, $t_p = 8.3$ ms half sine wave	240	A		
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	$V_{BR}$ , $V_{R}$	I <sub>R</sub> = 100 μA	600	-	-		
Forward voltage		I <sub>F</sub> = 30 A	-	1.36	1.6		
	V <sub>F</sub>	I <sub>F</sub> = 60 A	-	1.6	-	V	
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C	-	1.23	-		
		I <sub>F</sub> = 60 A, T <sub>J</sub> = 125 °C	-	1.5	-		
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.19	1.35		
		I <sub>F</sub> = 60 A, T <sub>J</sub> = 150 °C	-	1.48	-		
Reverse leakage current	I <sub>R</sub>	V <sub>R</sub> = V <sub>R</sub> rated	-	-	50		
neverse leakage current		$T_J = 125$ °C, $V_R = V_R$ rated	-	-	500	μA	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	18.3	-	pF	



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS MIN. TYP.					UNITS	
Payarea raceyony timo	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 30 A dI <sub>F</sub> /dt = 1000 A/μs V <sub>R</sub> = 400 V	-	65	-	- ns	
Reverse recovery time		T <sub>J</sub> = 125 °C		-	90	-		
Dook recovery ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	18	-	A	
Peak recovery current		T <sub>J</sub> = 125 °C		-	32	-		
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		-	850	-	nC	
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	1850	-		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	0.9			
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	40	°C/W		
Thermal resistance, case to heatsink	R <sub>thCS</sub>		-	0.4	-			
Weight			-	6.0	-	g		
weignt			-	0.21	-	oz.		
Mounting torque			6.0 (5)	-	12 (10)	kgf · cm (lbf · in)		
Marking device		Case style TO-247AD 2L	E4PU3006L			•		

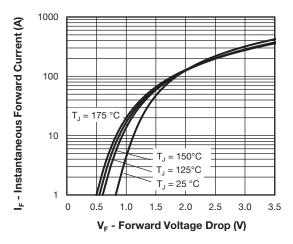


Fig. 1 - Typical Forward Voltage Drop Characteristics

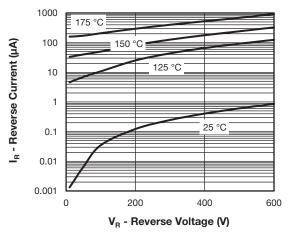


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

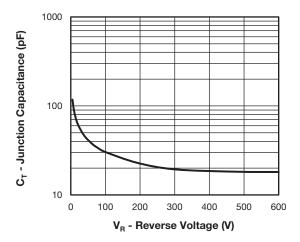


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

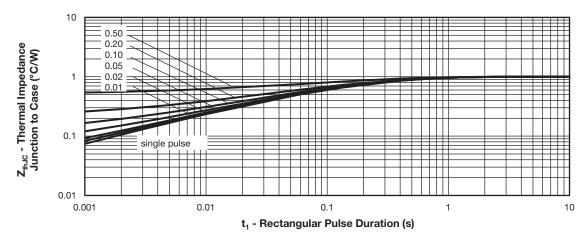


Fig. 4 - Max. Thermal Impedance Z<sub>thJC</sub> Characteristics

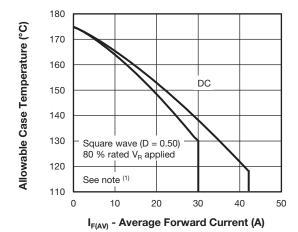


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

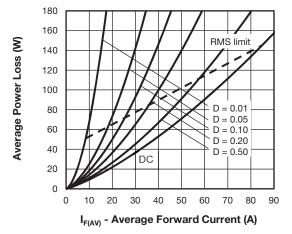


Fig. 6 - Forward Power Loss Characteristics

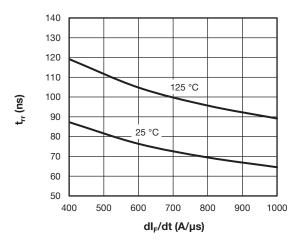
#### Note

<sup>(1)</sup> Formula used: T<sub>C</sub> = T<sub>J</sub> - (P<sub>d</sub> + P<sub>dREV</sub>) x R<sub>thJC</sub>; Pd = forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see Fig.5) P<sub>dREV</sub> = inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R</sub> = rated V<sub>R</sub>



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# Vishay Semiconductors



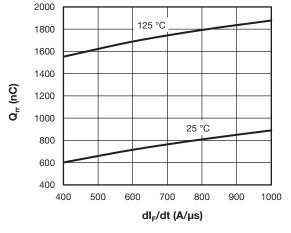


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

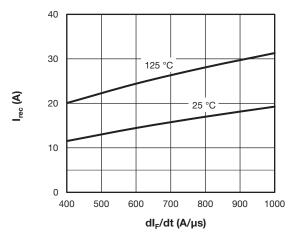
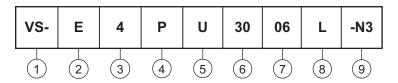


Fig. 9 - Typical Reverse Current vs. dl<sub>F</sub>/dt



### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Circuit configuration:

E = single diode

3 - FRED Pt Gen 4

4 - P = TO-247 package

5 - Process type:

U = ultrafast recovery

6 - Current rating (30 = 30 A)

7 - Voltage rating (06 = 600 V)

8 - Package: L = long lead

9 - Environmental digit:

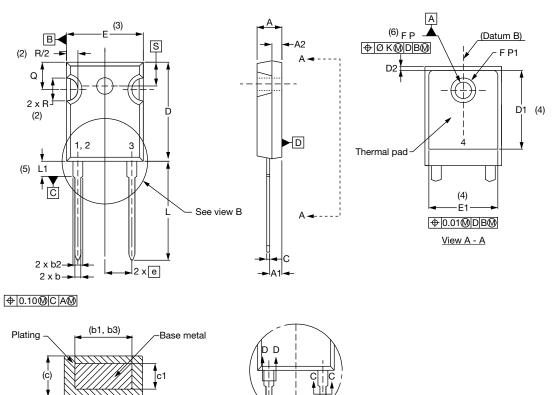
-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-E4PU3006L-N3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95536</u>					
Part marking information	www.vishay.com/doc?95648				

### **TO-247AD 2L**

### **DIMENSIONS** in millimeters and inches



View B

SYMBOL	MILLIN	MILLIMETERS		INCHES		
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.65	5.31	0.183	0.209		
A1	2.21	2.59	0.087	0.102		
A2	1.50	2.49	0.059	0.098		
b	0.99	1.40	0.039	0.055		
b1	0.99	1.35	0.039	0.053		
b2	1.65	2.39	0.065	0.094		
b3	1.65	2.34	0.065	0.092		
С	0.38	0.89	0.015	0.035		
c1	0.38	0.84	0.015	0.033		
D	19.71	20.70	0.776	0.815	3	
D1	13.08	-	0.515	-	4	
D2	0.51	1.35	0.020	0.053		

Section C - C, D - D

SYMBOL	MILLIN	IETERS	INC	INCHES		
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Е	15.29	15.87	0.602	0.625	3	
E1	13.46	-	0.53	-		
е	5.46	BSC	0.215	BSC		
ØK	0.2	254	0.0	0.010		
L	19.81	20.32	0.780	0.800		
L1	3.71	4.29	0.146	0.169		
ØΡ	3.56	3.66	0.14	0.144		
Ø P1	-	6.98	-	0.275		
Q	5.31	5.69	0.209	0.224		
R	4.52	5.49	0.178	0.216		
S	5.51 BSC		0.217	BSC		
	•		•	•		

#### **Notes**

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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